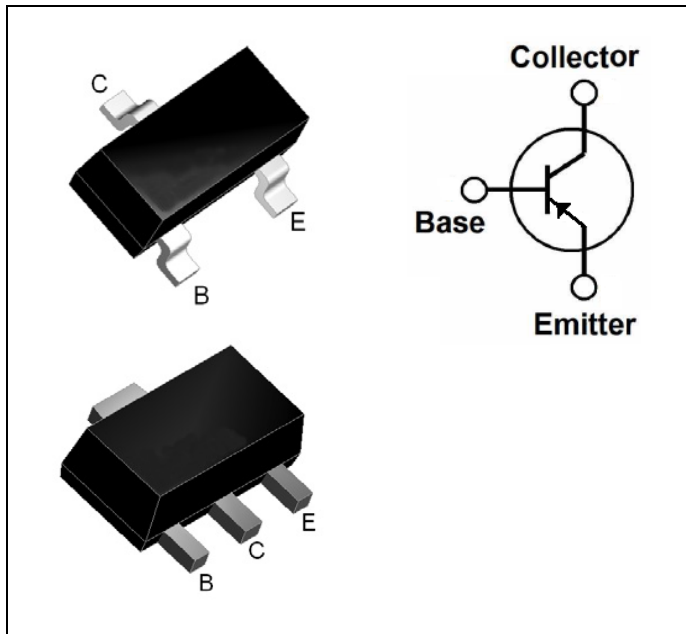


GENERAL PURPOSE TRANSISTORS PNP Silicon



FEATURES

- Low Collector-Emitter Saturation Voltage $V_{CE(sat)}$ And Corresponding Low $R_{CE(sat)}$
- High Collector Current Capability
- High Collector Current Gain
- Improved Efficiency Due to Reduced Heat Generation

MECHANICAL DATA

- Available in SOT-23 , SOT-89 Package
- Solderability : MIL-STD-202, Method 208
- Full RoHS Compliance

ORDERING INFORMATION

| Part Number | Package | Shipping | Marking Code |
|--------------|---------|-----------|-----------------|
| LST5350□-T3R | SOT-23 | Tape Reel | 53yww |
| LST5350□-T89 | SOT-89 | Tape Reel | T5350 LS YWW |

Note:

1. □: none is for Lead Free package;
"G" is for Halogen Free package.
2. Marking Code: yww: y: Year code; ww: Week code.

THERMAL DATA

| PARAMETER | | SYMBOL | VALUES | UNIT |
|---|--------|-----------------|--------|------|
| Thermal Resistance, Junction-to-Ambient | SOT-23 | $R_{\theta JA}$ | 417 | °C/W |
| | SOT-89 | | 225 | |

Note:

3. $R_{\theta JA}$ is measured with device mounted on 1 in² FR-4 board with 2 oz copper.

ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise specified. (Note 1)

| PARAMETER | SYMBOL | RATING | UNIT |
|--|----------------------|-------------|------|
| Collector-Emitter Voltage | V _{CEO} | -50 | V |
| Collector-Base Voltage | V _{CBO} | -50 | V |
| Emitter-Base Voltage | V _{EBO} | -5 | V |
| Equivalent On-Resistance | R _{CE(sat)} | 135 | mΩ |
| Collector Current (Continuous) | SOT-23 | -2 | A |
| | SOT-89 | -3 | |
| Repetitive Peak Collector Current (Note 2) | SOT-23 | -3 | |
| Peak Collector Current (Note 3) | I _{CM} | -5 | |
| Total Device Dissipation | SOT-23 | 300 | mW |
| | SOT-89 | 550 | |
| Junction Temperature | T _J | 150 | °C |
| Storage Temperature Range | T _{stg} | - 65 ~ +150 | °C |

Note:

1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.
2. Operated under pulsed conditions: pulse width t_p ≤ 100 ms; duty cycle δ ≤ 0.25.
3. Single peak

ELECTRICAL CHARACTERISTICS

T_A = 25°C, unless otherwise noted.

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------------------------|----------------------|--|------|-----|------|------|
| OFF CHARACTERISTICS | | | | | | |
| Collector-Emitter Breakdown Voltage | V _{(BR)CEO} | I _C = -1mA, I _B = 0 | -50 | | | V |
| Collector-Base Breakdown Voltage | V _{(BR)CBO} | I _C = -10μA, I _E = 0 | -50 | | | V |
| Emitter-Base Breakdown Voltage | V _{(BR)EBO} | I _E = -10μA, I _C = 0 | -5 | | | V |
| Emitter-Base Cut-off Current | I _{EBO} | V _{EB} = -5V, I _C = 0 | | | -100 | nA |
| Collector-Base Cut-off Current | I _{CBO} | V _{CB} = -50V, I _E = 0 | | | -100 | nA |
| | | V _{CB} = -50V, I _E = 0, T _J = 150°C | | | -50 | μA |
| ON CHARACTERISTICS | | | | | | |
| Dc Current Gain | h _{FE} | V _{CE} = -2V, I _C = -100mA | 200 | | | - |
| | | V _{CE} = -2V, I _C = -500mA | 200 | | | |
| | | V _{CE} = -2V, I _C = -1A | 200 | | | |
| | | V _{CE} = -2V, I _C = -2A | 130 | | | |
| | | V _{CE} = -2V, I _C = -3A | 80 | | | |
| Collector-Emitter Saturation Voltage | V _{CE(sat)} | I _C = -500mA, I _B = -50mA | | | -90 | mV |
| | | I _C = -1A, I _B = -50mA | | | -180 | |
| | | I _C = -2A, I _B = -100mA | | | -320 | |
| | | I _C = -2A, I _B = -200mA | | | -270 | |
| | | I _C = -3A, I _B = -300mA | | | -390 | |
| Equivalent On-Resistance | R _{CE(sat)} | I _C = -2A, I _B = -200mA | | 90 | 135 | mΩ |
| Base-Emitter Saturation Voltage | V _{BE(sat)} | I _C = -2A, I _B = -100mA | | | -1.1 | V |
| | | I _C = -3A, I _B = -300mA | | | -1.2 | |
| Base-Emitter Turn-on Voltage | V _{BE(on)} | V _{CE} = -2V, I _C = -1A | -1.2 | | | V |

SMALL-SIGNAL CHARACTERISTICS

| | | | | | | |
|-----------------------|-------|--|-----|--|----|-----|
| Transition Frequency | f_T | $V_{CE} = -5V, I_C = -100mA, f = 100MHz$ | 100 | | | MHz |
| Collector Capacitance | C_C | $V_{CB} = -10V, I_E = I_e = 0, f = 1MHz$ | | | 35 | pF |

ELECTRICAL CHARACTERISTICS CURVE

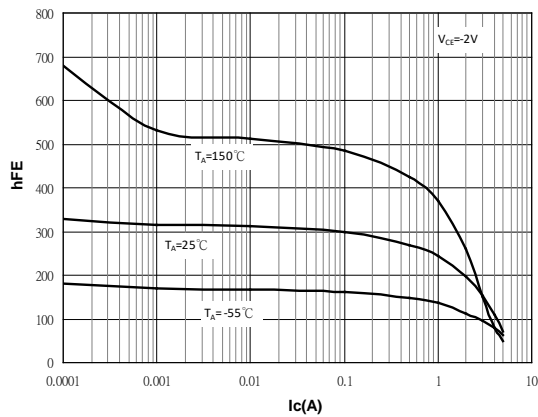


FIG.1 - DC current gain as a function of collector current

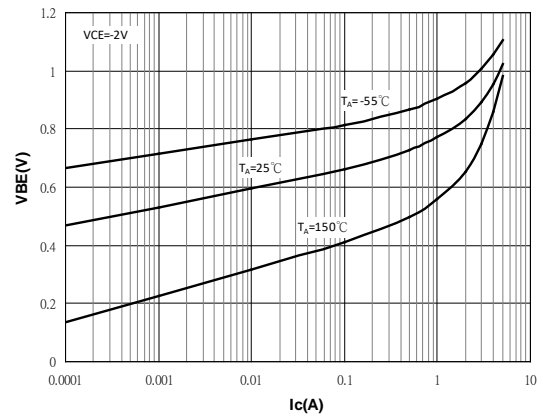


FIG.2 - Base-emitter voltage as a function of collector current

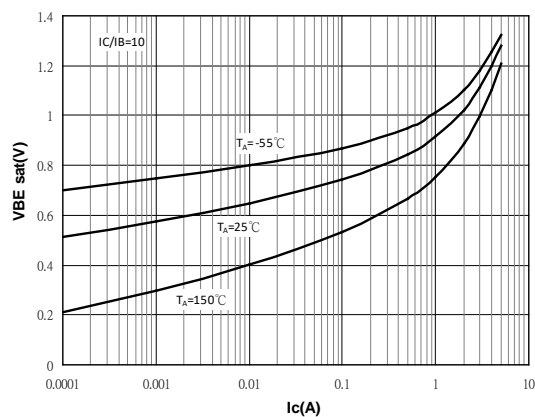


FIG.3 - Base-emitter saturation voltage as a function of collector current

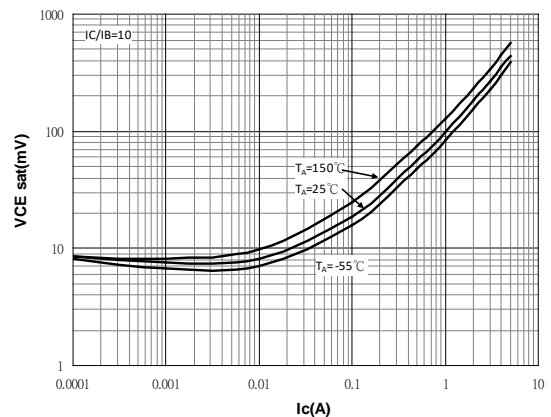


FIG.4 - Collector-emitter saturation voltage as a function of collector current

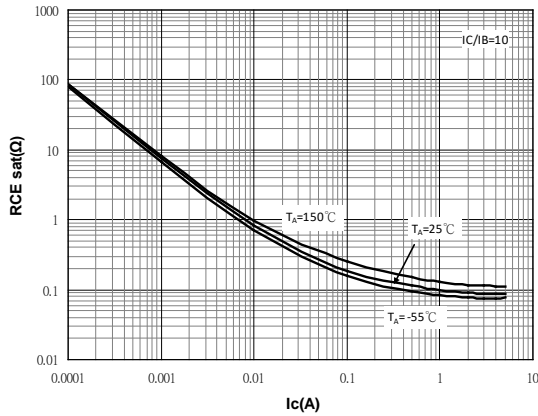


FIG.5 - Equivalent on-resistance as a function of collector current

PHYSICAL DIMENSION

Unit : Inch (Millimeter)

